

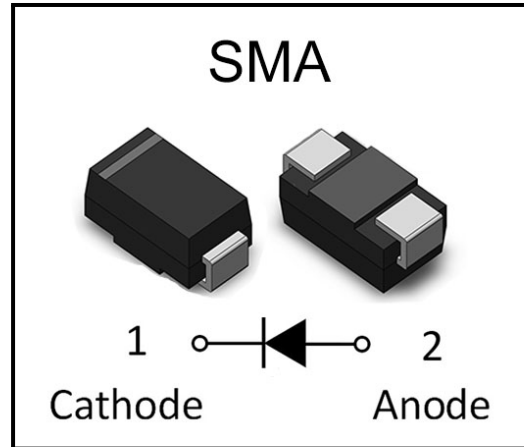
# US2A-US2M

Fast Recovery  
Rectifier Diode

## Features

- Super fast switching time for high efficiency
- Low forward voltage drop
- High current capability
- High reliability
- High surge current capability
- Epitaxial construction

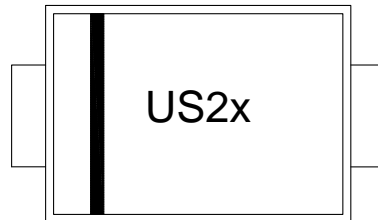
## Package



## Description

- Case: molded plastic
- Polarity: Color band denotes cathode
- Package: SMA Plastic Package

## Making Code



## Ordering information

Part Number	US2A	US2B	US2D	US2G	US2J	US2K	US2M
Marking	US2A	US2B	US2D	US2G	US2J	US2K	US2M
Base qty	5K	5K	5K	5K	5K	5K	5K



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Maximum Ratings (@T<sub>A</sub>=25°C unless otherwise noted)

Symbol	Characteristics	US2A	US2B	US2D	US2G	US2J	US2K	US2M	Unit	
V <sub>RRM</sub>	Maximum Recurrent Peak Reverse Voltage	50	100	200	400	600	800	1000	V	
V <sub>RMS</sub>	Maximum RMS Voltage	35	70	140	280	420	560	700	V	
V <sub>DC</sub>	Maximum DC Blocking Voltage	50	100	200	400	600	800	1000	V	
I <sub>(AV)</sub>	Maximum Average Forward Rectified Current at T <sub>L</sub> = 110°C	2.0							A	
I <sub>FSM</sub>	Peak Forward Surge Current 8.3ms Single half sine-wave Superimposed on Rated Load	50							A	
V <sub>F</sub>	Maximum Forward Voltage at 1.0A DC	1.0		1.3		1.7		V		
I <sub>R</sub>	Maximum DC Reverse Current T <sub>J</sub> = 25°C at Rated DC Blocking Voltage T <sub>J</sub> = 125°C	5				100				uA
T <sub>RR</sub>	Maximum Reverse Recovery Time(Note1)	50				100				nS
C <sub>J</sub>	Typical Junction Capacitance(Note2)	50							pF	
R <sub>θJA</sub>	Typical Thermal Resistance(Note3)	60							°C/W	
T <sub>J</sub>	Operating Temperature Range	-55 to +150							°C	
T <sub>STG</sub>	Storage Temperature Range	-55 to +150							°C	

Notes:(1)Reverse recovery condition I<sub>F</sub>=0.5A,I<sub>R</sub>=1.0A,I<sub>RR</sub>=0.25A.

(2) Measured at 1.0 MHz and applied reverse voltage of 4.0V DC.

(3)Thermal resistance junction to ambient.



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Typical Performance Characteristics ( $T_J = 25^\circ\text{C}$ , unless otherwise noted)

Figure 1: Typical Forward Characteristics

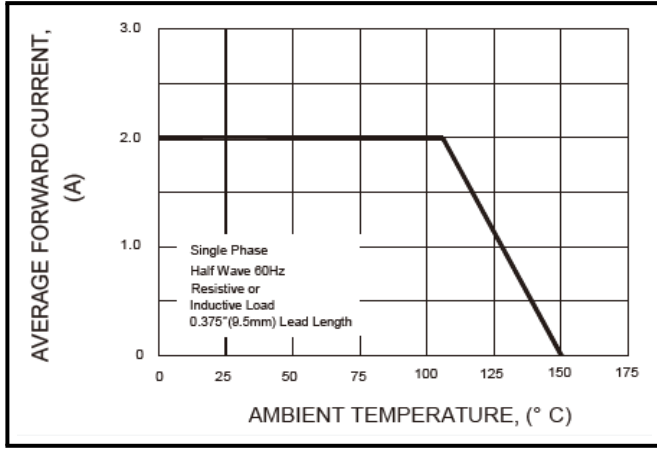


Figure 2: Typical Junction Capacitance

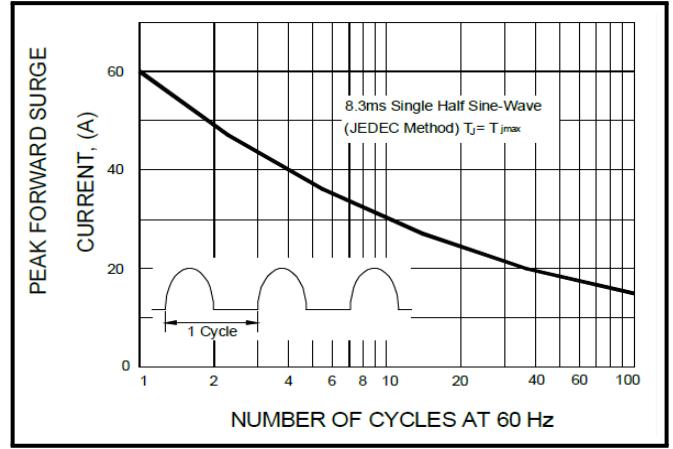


Figure 3: Forward Current Derating Curve

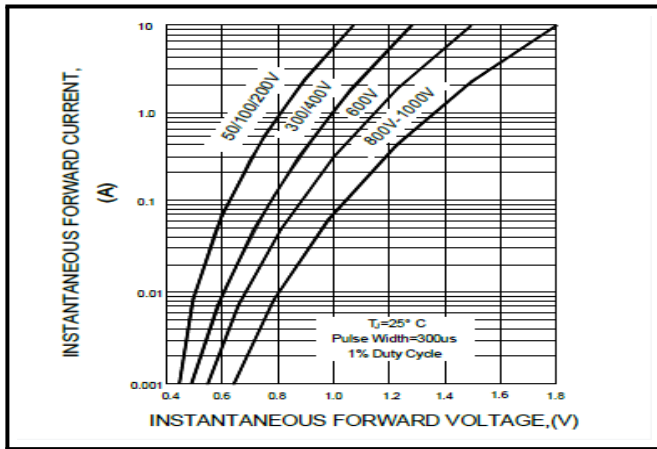


Figure 4: Peak Forward Surge Current

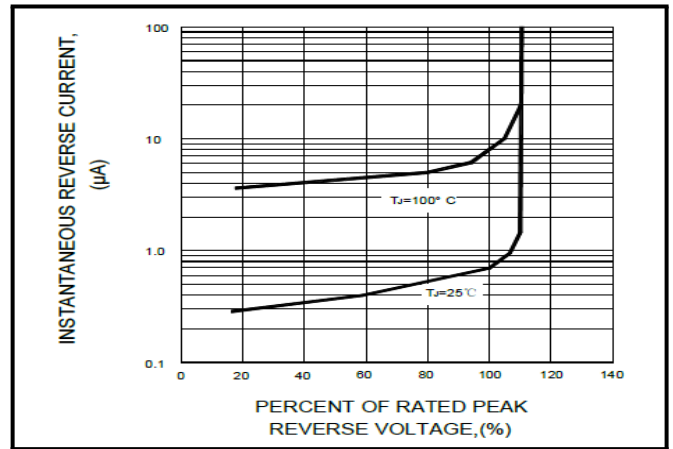


Figure 5: Typical Junction Capacitance

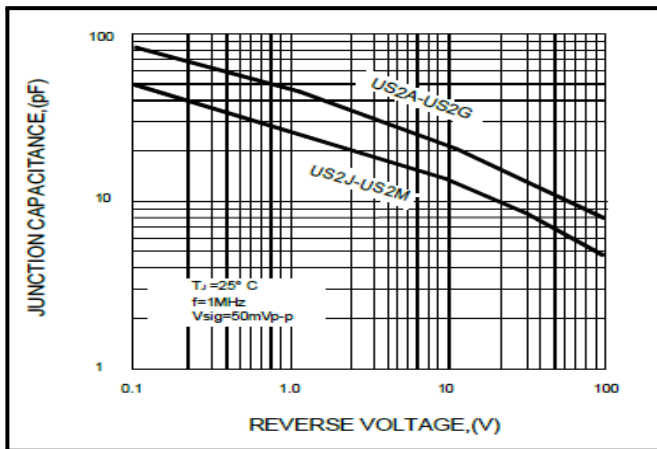
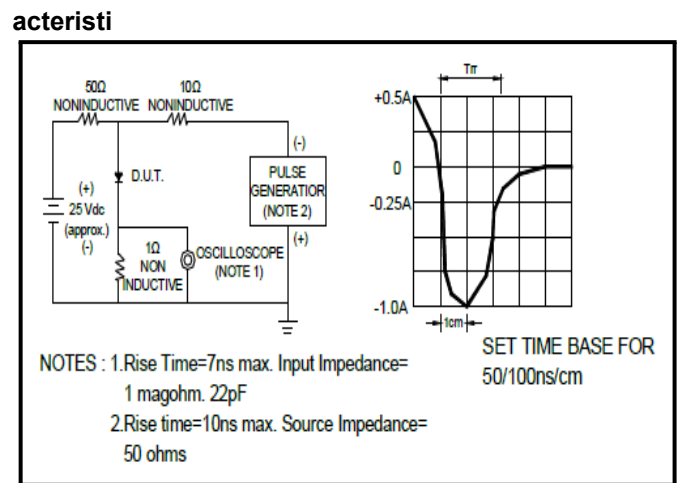
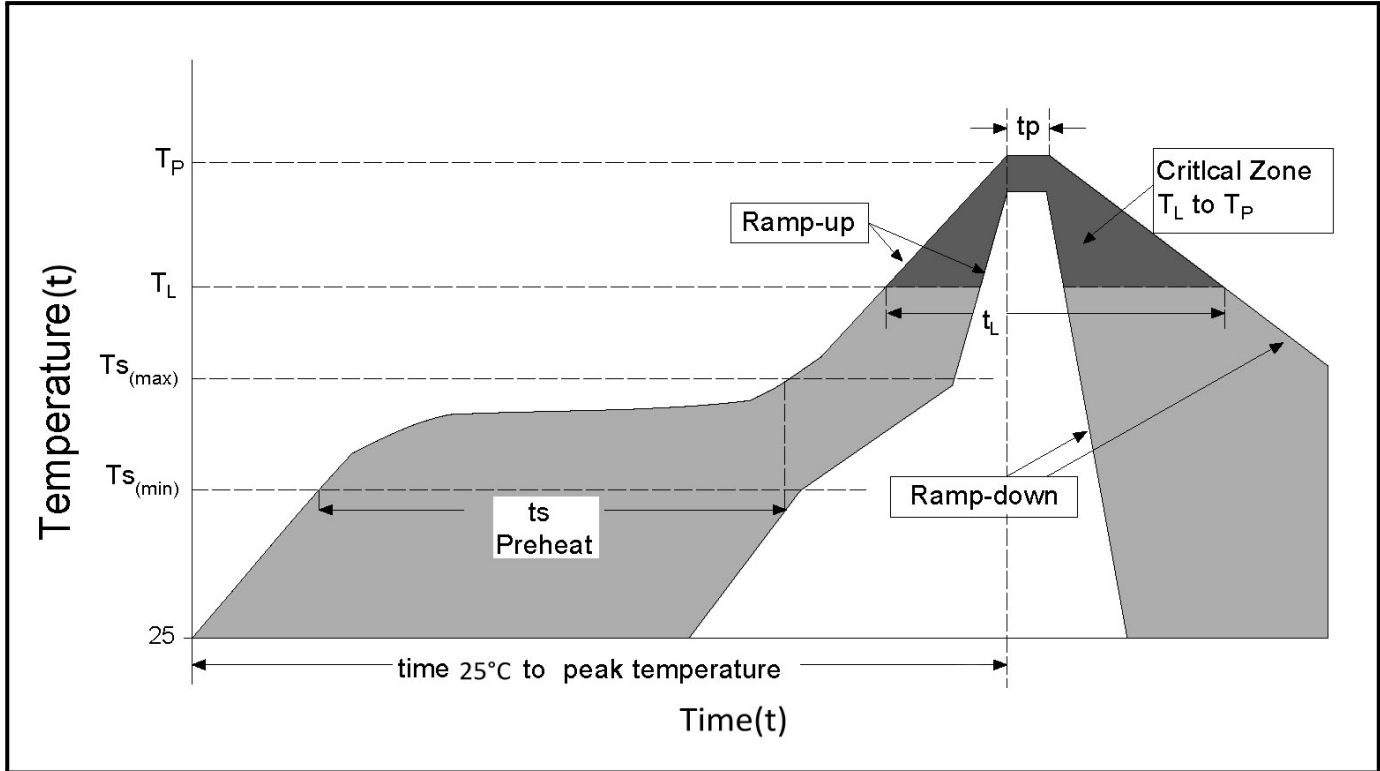


Figure 6: Test Circuit Diagram And Recover Time Characteristi



**Soldering Parameters**



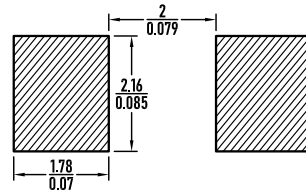
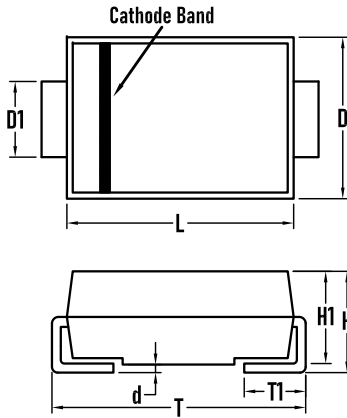
Reflow Condition		Lead-free assembly
Pre Heat	- Temperature Min ( $T_{S(min)}$ )	150°C
	- Temperature Max ( $T_{S(max)}$ )	200°C
	- Time (min to max) ( $t_s$ )	60 - 180 secs
Average ramp up rate (Liquidus Temp ( $T_L$ ) to peak)		3°C/second max
$T_{S(max)}$ to $T_L$ - Ramp-up Rate		3°C/second max
Reflow	- Temperature ( $T_L$ ) (Liquidus)	217°C
	- Time ( $t_L$ )	60 - 150 secs
Peak Temperature ( $T_P$ )		260 <sup>+0/-5</sup> °C
Time within 5°C of actual peak Temperature ( $t_p$ )		20 - 40 secs
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (t)		8 minutes Max.
Do not exceed		260°C



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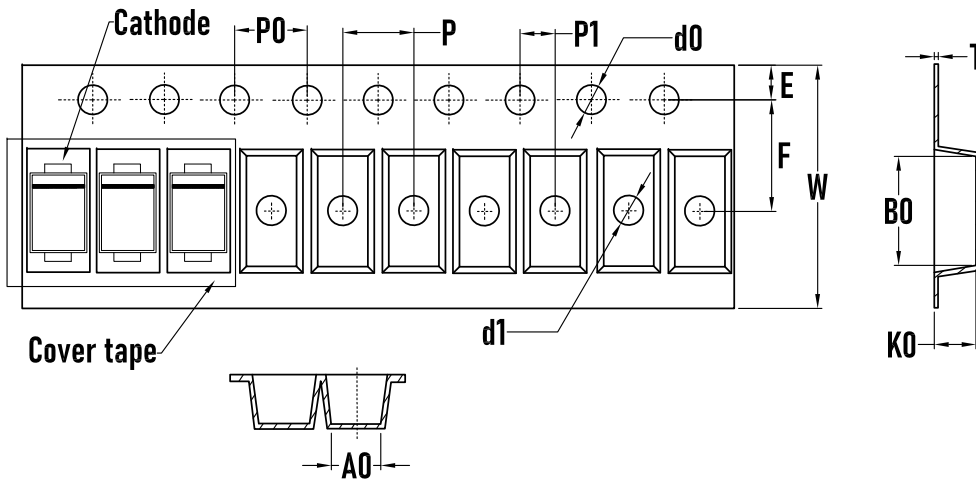
## Outline Drawing - SMA



Note:  
dimension :  $\frac{\text{mm}}{\text{inch}}$

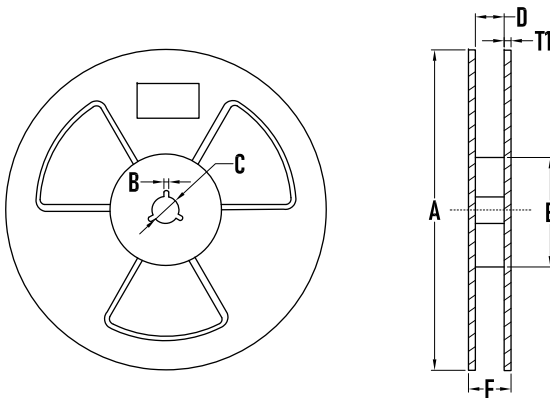
SYMBOL	MILLIMETER		Inches	
	MIN.	MAX.	MIN.	MAX.
D	2.5	2.9	0.098	0.114
D1	1.2	1.8	0.047	0.071
T	4.8	5.3	0.189	0.209
T1	0.8	1.5	0.031	0.059
d	-	0.2	-	0.008
H1	1.8	2.2	0.071	0.087
H	1.9	2.5	0.075	0.098
L	3.9	4.6	0.154	0.181

## Packaging Tape - SMA



SYMBOL	MILLIMETER
A0	2.70
B0	5.10±0.1
d0	1.50±0.1
d1	1.50±0.1
E	1.75±0.1
F	5.50±0.1
K0	2.40±0.1
P	4.00±0.1
P0	4.00±0.1
P1	2.00±0.1
W	12.00±0.1
T	0.2±0.02

## Packaging Reel



SYMBOL	MILLIMETER
A	323±2
B	3.0±0.2
C	15.0±0.5
D	13±2
E	73±2
T1	2.2±0.2
Quantity	5000PCS

